



CSD23202W10T Information



For Reference Only

Part Number CSD23202W10T **Manufacturer** Texas Instruments

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET P-CH 12V 2.2A 4DSBGA

Package 4-UFBGA, DSBGA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









CSD23202W10T Specifications

Manufacturer Part Number	CSD23202W10T
Manufacturer	Texas Instruments
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	4-UFBGA, DSBGA
Series	NexFET?
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	12V
Current - Continuous Drain (Id) @ 25°C	2.2A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	1.5V, 4.5V
Vgs(th) (Max) @ Id	900mV @ 250μA
Gate Charge (Qg) (Max) @ Vgs	3.8nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	512pF @ 6V
Vgs (Max)	-6V
FET Feature	-
Power Dissipation (Max)	1W (Ta)
Rds On (Max) @ Id, Vgs	53 mOhm @ 500mA, 4.5V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	4-DSBGA (1x1)
Package / Case	4-UFBGA, DSBGA
	Report errors?

CSD23202W10T Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

CSD23202W10T Payment Methods



















CSD23202W10T Shipping Methods













If you have any question about CSD23202W10T, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com